

74HC30D,653 Datasheet



DiGi Electronics Part Number Manufacturer Manufacturer Product Number Description Detailed Description

74HC30D,653-DG Nexperia USA Inc. 74HC30D,653 IC GATE NAND 1CH 8-INP 14SO NAND Gate IC 1 Channel 14-SO

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Manufacturer Product Number:	Manufacturer:
74HC30D,653	Nexperia USA Inc.
Series:	Product Status:
74HC	Active
Logic Type:	Number of Circuits:
NAND Gate	1
Number of Inputs:	Features:
8	
Voltage - Supply:	Current - Quiescent (Max):
2V ~ 6V	2 μΑ
Current - Output High, Low:	Input Logic Level - Low:
5.2mA, 5.2mA	0.5V ~ 1.8V
Input Logic Level - High:	Max Propagation Delay @ V, Max CL:
1.5V ~ 4.2V	22ns @ 6V, 50pF
Operating Temperature:	Mounting Type:
-40°C ~ 125°C	Surface Mount
Supplier Device Package:	Package / Case:
14-50	14-SOIC (0.154", 3.90mm Width)
Base Product Number:	
74HC30	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0001	

8-input NAND gate Rev. 10 — 13 March 2024

Product data sheet

1. General description

The 74HC30; 74HCT30 is an 8-input NAND gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- Input levels:
 - For 74HC30: CMOS level
 - For 74HCT30: TTL level
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

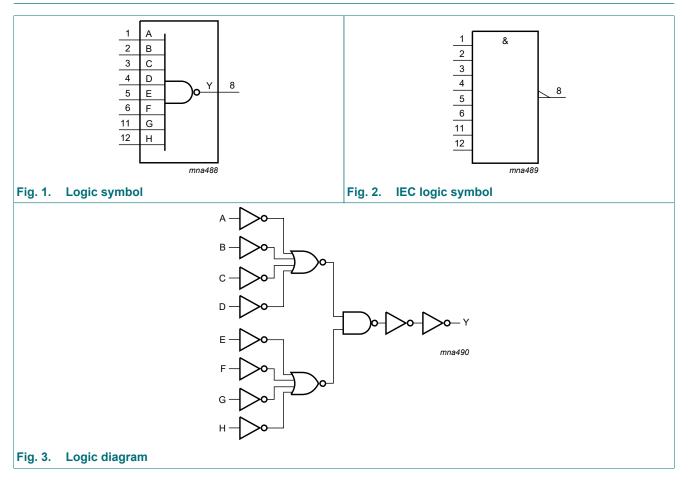
Table 1. Ordering information

Type number	Package										
	Temperature range	Name	Description	Version							
74HC30D	-40 °C to +125 °C	SO14	plastic small outline package; 14 leads;	<u>SOT108-1</u>							
74HCT30D			body width 3.9 mm								
74HC30PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1							
74HCT30PW			body width 4.4 mm								

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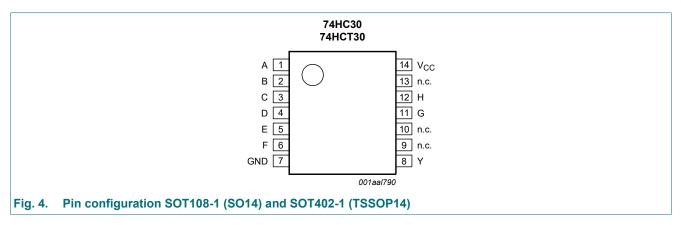
8-input NAND gate

4. Functional diagram



5. Pinning information





8-input NAND gate

5.2. Pin description

Symbol	Pin	Description
A	1	data input
В	2	data input
С	3	data input
D	4	data input
E	5	data input
F	6	data input
GND	7	ground (0 V)
Y	8	data output
n.c.	9	not connected
n.c.	10	not connected
G	11	data input
Н	12	data input
n.c.	13	not connected
V _{CC}	14	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Input								Output
Α	В	С	D	E	F	G	Н	Y
L	Х	Х	Х	Х	Х	Х	Х	Н
Х	L	Х	Х	Х	Х	Х	Х	Н
Х	Х	L	Х	Х	Х	Х	Х	Н
Х	Х	Х	L	Х	Х	Х	Х	Н
Х	Х	Х	Х	L	Х	Х	Х	Н
Х	Х	Х	Х	Х	L	Х	Х	Н
Х	Х	Х	Х	Х	Х	L	Х	Н
Х	Х	Х	Х	Х	Х	Х	L	Н
Н	Н	Н	Н	Н	Н	Н	Н	L

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
l _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{CC} + 0.5 V	[1]	-	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	$-0.5 V < V_O < V_{CC} + 0.5 V$		-	±25	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation		[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT108-1 (SO14) package: P_{tot} derates linearly with 10.1 mW/K above 100 °C.

For SOT402-1 (TSSOP14) package: Ptot derates linearly with 7.3 mW/K above 81 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC30		74HCT30			Unit	
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

8-input NAND gate

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
74HC30	1	1								
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	2.0	-	20	-	40	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

74HC30; 74HCT30

8-input NAND gate

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	
74HCT3	0									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}		$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	2.0	-	20	-	40	μA
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.4 \text{ V}; I_O = 0 \text{ A};$ other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	60	216	-	275	-	294	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; $C_L = 50 pF$; for test circuit see Fig. 6.

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
74HC30						•	1			
	propagation delay	A, B, C, D, E, F, G, H to Y; [1] see Fig. 5								
		V _{CC} = 2.0 V	-	41	130	-	165	-	195	ns
		V _{CC} = 4.5 V	-	15	26	-	33	-	39	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	12	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	12	22	-	28	-	33	ns
t _t	transition	see <u>Fig. 5</u> [2]								
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
C _{PD}	power dissipation capacitance	per package; [3] V _I = GND to V _{CC}	-	15	-	-	-	-	-	pF

74HC_HCT30

74HC30; 74HCT30

8-input NAND gate

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Мах	1
74HCT30										
t _{pd}	propagation delay	A, B, C, D, E, F, G, H to Y; [1] see <u>Fig. 5</u>								
		V _{CC} = 4.5 V	-	16	28	-	35	-	42	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	12	-	-	-	-	-	ns
t _t	transition time	$V_{CC} = 4.5 V$; see <u>Fig. 5</u> [2]	-	7	15	-	19	-	22	ns
C _{PD}	power dissipation capacitance	per package; [3] V _I = GND to V _{CC} - 1.5 V	-	15	-	-	-	-	-	pF

 t_{pd} is the same as t_{PHL} and t_{PLH} . [1]

[2]

 t_t is the same as t_{THL} and t_{TLH} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W): [3]

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

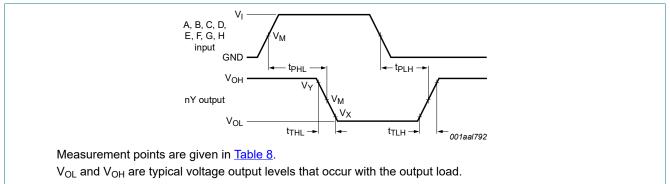
 C_1 = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

10.1. Waveforms and test circuit



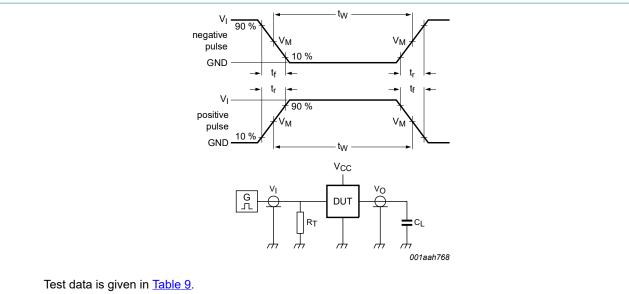
Input to output propagation delays and output transition times Fig. 5.

Table 8. Measurement points

Туре	Input	Output						
	V _M	V _M	V _X	V _Y				
74HC30	0.5V _{CC}	0.5V _{CC}	0.1V _{CC}	0.9V _{CC}				
74HCT30	1.3 V	1.3 V	0.1V _{CC}	0.9V _{CC}				

74HC30; 74HCT30

8-input NAND gate



Definitions for test circuit:

 R_{T} = termination resistance should be equal to the output impedance Z_{o} of the pulse generator.

 C_L = load capacitance including jig and probe capacitance.

Fig. 6. Test circuit for measuring switching times

Table 9. Test data

Туре	Input		Load	Test
	VI	t _r , t _f	CL	
74HC30	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74HCT30	3.0 V	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

8-input NAND gate

11. Package outline

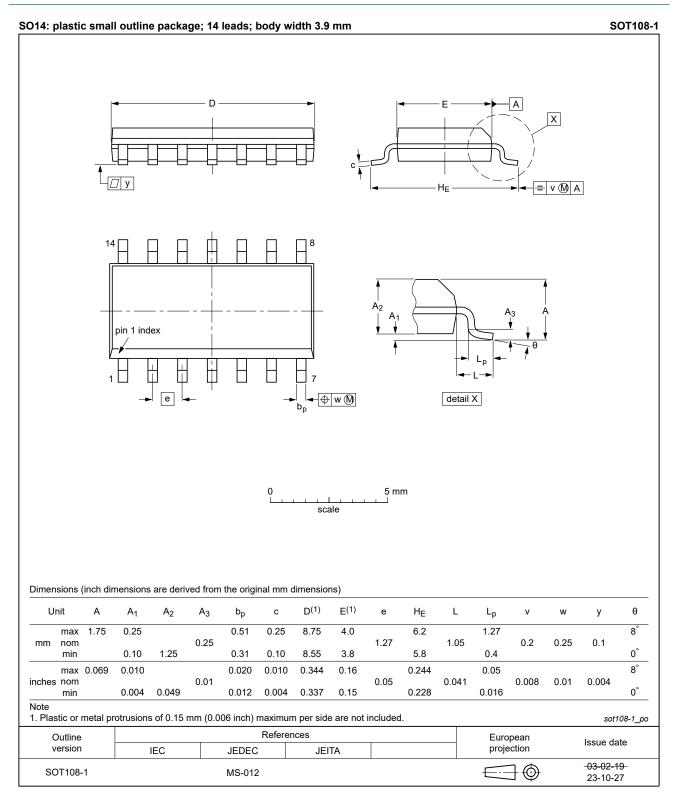
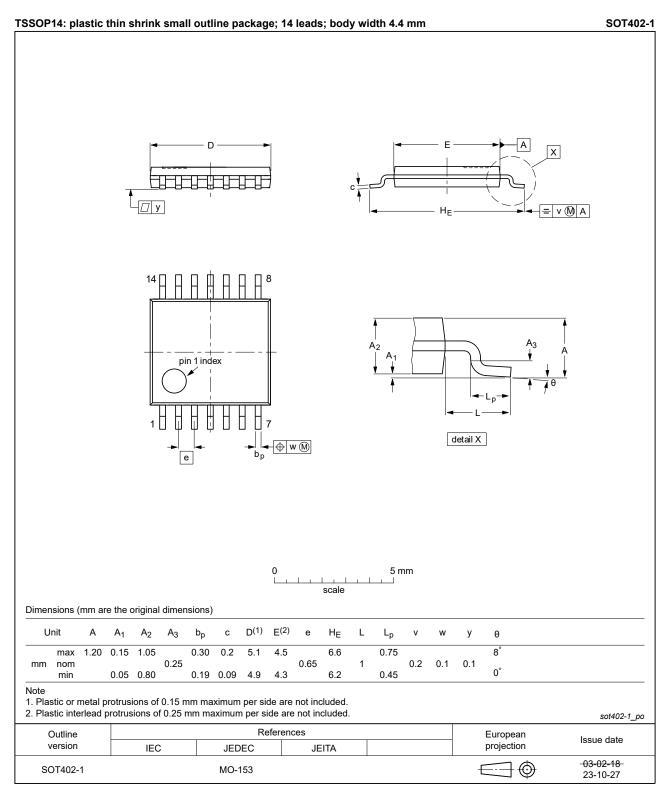


Fig. 7. Package outline SOT108-1 (SO14)

74HC30; 74HCT30

8-input NAND gate





12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model

74HC_HCT30

8-input NAND gate

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT30 v.10	20240313	Product data sheet	-	74HC_HCT30 v.9
Modifications:		D specification updated accor <u>g. 8</u> : Aligned SO and TSSOP p	0	
74HC_HCT30 v.9	20210906	Product data sheet	-	74HC_HCT30 v.8
Modifications:	Type number 74HCT30DB (SOT337-1 / SSOP14) removed.			
74HC_HCT30 v.8	20210209	Product data sheet	-	74HC_HCT30 v.7
Modifications:	 Nexperia. Legal texts hat Section 2 upon Section 7: Design 1 	f this data sheet has been rede ave been adapted to the new o dated. erating values for P _{tot} total pow 74HC30DB (SOT337-1 / SSC	company name wher	e appropriate.
74HC_HCT30 v.7	20151202	Product data sheet	-	74HC_HCT30 v.6
Modifications:	Type numbers 74HC30N and 74HCT30N (SOT27-1) removed.			
74HC_HCT30 v.6	20121227	Product data sheet	-	74HC_HCT30 v.5
Modifications:	New general description.			
74HC_HCT30 v.5	20111213	Product data sheet	-	74HC_HCT30 v.4
Modifications:	Legal pages updated.			
74HC_HCT30 v.4	20100504	Product data sheet	-	74HC_HCT30 v.3
74HC_HCT30 v.3	20100420	Product data sheet	-	74HC_HCT30 v.2
74HC_HCT30 v.2	19970829	Product specification	-	-

8-input NAND gate

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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74HC30; 74HCT30

8-input NAND gate

Contents

1. General description	1
2. Features and benefits	1
3. Ordering information	1
4. Functional diagram	2
5. Pinning information	2
5.1. Pinning	2
5.2. Pin description	3
6. Functional description	3
7. Limiting values	4
8. Recommended operating conditions	4
9. Static characteristics	5
10. Dynamic characteristics	6
10.1. Waveforms and test circuit	7
11. Package outline	9
12. Abbreviations	10
13. Revision history	11
14. Legal information	12

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74HC_HCT30



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Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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